Current Transfer Ratio

Type	Classification *1	Current Transfer Ratio (%) (I_C / I_F) I_F = 5mA, V_{CE} = 5V, Ta = 25°C		Marking Of Classification
		Min.	Max.	
TLP121	(None)	50	600	BLANK, Y, Y■, G, G■, B, B■, GB
	Rank Y	50	150	Y, Y■
	Rank GR	100	300	G, G■
	—	200	600	B, B■
	Rank GB	100	600	G, G■, B, B■, GB

*1: Ex, rank GB: TLP121 (GB)

Note: Application type name for certification test, please use standard product type name, i, e.
TLP121 (GB): TLP121

Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
LED	Forward current	I_F	50	mA
	Forward current derating	ΔI_F / °C	−0.7 (Ta ≥ 53°C)	mA / °C
	Pulse forward current	I_{FP}	1 (100μs pulse, 100pps)	A
	Reverse voltage	V_R	5	V
	Junction temperature	T_j	125	°C
Detector	Collector−emitter voltage	V_{CEO}	80	V
	Emitter−collector voltage	V_{ECO}	7	V
	Collector current	I_C	50	mA
	Collector power dissipation	P_C	150	mW
	Collector power dissipation derating (Ta ≥ 25°C)	ΔP_C / °C	−1.5	mW / °C
	Junction temperature	T_j	125	°C
Storage temperature range		T_{stg}	−55~125	°C
Operating temperature range		T_{opr}	−55~100	°C
Lead soldering temperature		T_{sol}	260 (10s)	°C
Total package power dissipation		P_T	200	mW
Total package power dissipation derating (Ta ≥ 25°C)		ΔP_T / °C	−2.0	mW / °C
Isolation voltage	(Note 1)	BV_S	3750 (AC, 1min., R.H. ≤ 60%)	Vrms

(Note 1) Device considered a two terminal device: Pins1, 3 shorted together and pins 4, 6 shorted together

Recommended Operating Conditions

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	V_{CC}	—	5	48	V
Forward current	I_F	—	16	20	mA
Collector current	I_C	—	1	10	mA
Operating temperature	T_{opr}	−25	—	85	°C

Individual Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
LED	Forward voltage	V_F	I_F = 10 mA	1.0	1.15	1.3	V
	Reverse current	I_R	V_R = 5 V	—	—	10	μA
	Capacitance	C_T	V = 0, f = 1 MHz	—	30	—	pF
Detector	Collector−emitter breakdown voltage	$V_{(BR)\ CEO}$	I_C = 0.5 mA	80	—	—	V
	Emitter−collector breakdown voltage	$V_{(BR)\ ECO}$	I_E = 0.1 mA	7	—	—	V
	Collector dark current	I_{CEO}	V_{CE} = 48 V	—	10	100	nA
			V_{CE} = 48 V, Ta = 85°C	—	2	50	μA
	Capacitance (collector to emitter)	C_{CE}	V = 0, f = 1 MHz	—	10	—	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	MIn.	Typ.	Max.	Unit
Current transfer ratio	I_C / I_F	I_F = 5 mA, V_{CE} = 5 V	50	—	600	%
		Rank GB	100	—	600	
Saturated CTR	I_C / $I_{F\ (sat)}$	I_F = 1 mA, V_{CE} = 0.4 V	—	60	—	%
		Rank GB	30	—	—	
Collector−emitter saturation voltage	$V_{CE\ (sat)}$	I_C = 2.4 mA, I_F = 8 mA	—	—	0.4	V
		I_C = 0.2 mA, I_F = 1 mA	—	0.2	—	
		Rank GB	—	—	0.4	
Off−state collector current	$I_{C\ (off)}$	V_F = 0.7V, V_{CE} = 48 V	—	1	10	μA

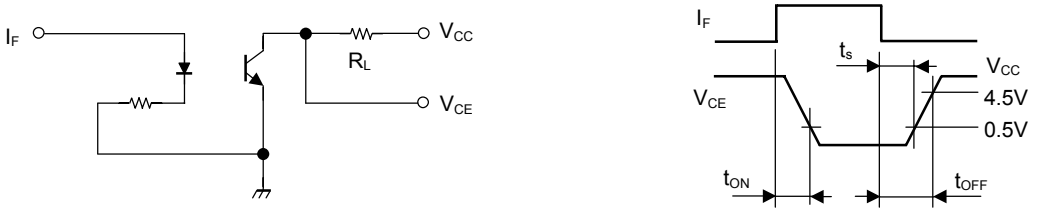
Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Capacitance (input to output)	C_S	V_S = 0, f = 1 MHz	—	0.8	—	pF
Isolation resistance	R_S	V_S = 500 V, R.H. ≤ 60%	5×10^{10}	10^{14}	—	Ω
Isolation voltage	BV_S	AC, 1 minute	3750	—	—	Vrms
		AC, 1 second, in oil	—	10000	—	
		DC, 1 minute, in oil	—	10000	—	Vdc

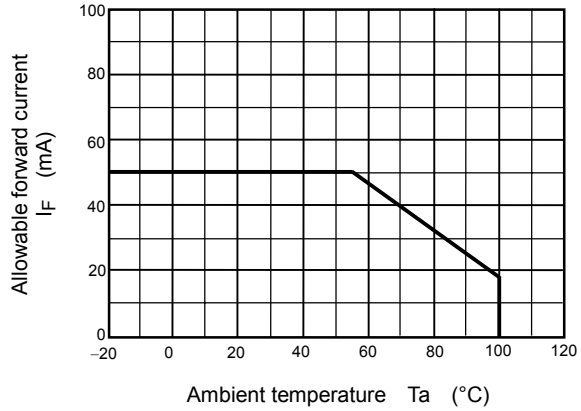
Switching Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Rise time	t_r	V_{CC} = 10 V, I_C = 2 mA R_L = 100Ω	—	2	—	μs
Fall time	t_f		—	3	—	
Turn−on time	t_{on}		—	3	—	
Turn−off time	t_{off}		—	3	—	
Turn−on time	t_{ON}	R_L = 1.9 kΩ (Fig.1) V_{CC} = 5 V, I_F = 16 mA	—	2	—	μs
Storage time	t_s		—	25	—	
Turn−off time	t_{OFF}		—	40	—	

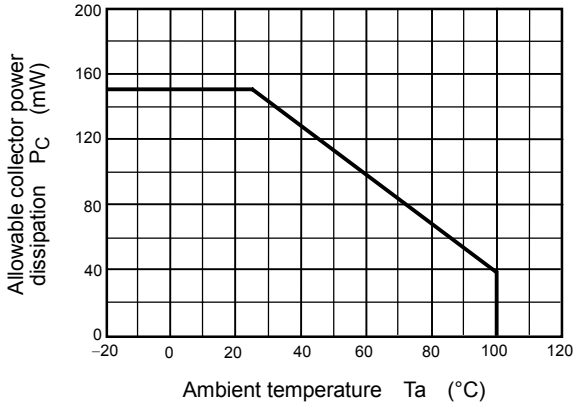
Fig. 1 Switching time test circuit



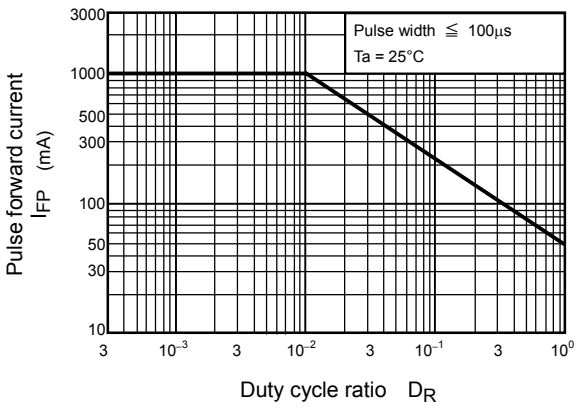
I_F – Ta



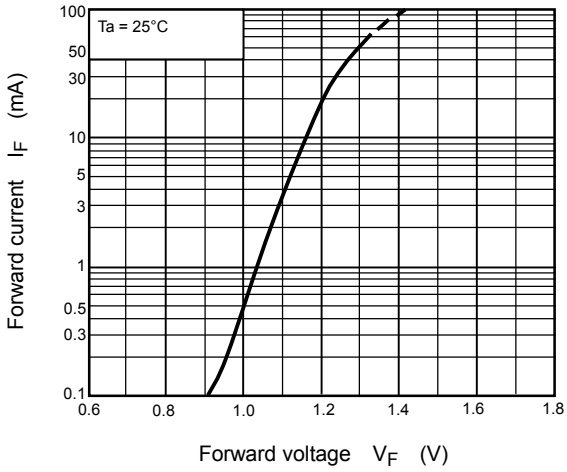
P_C – Ta



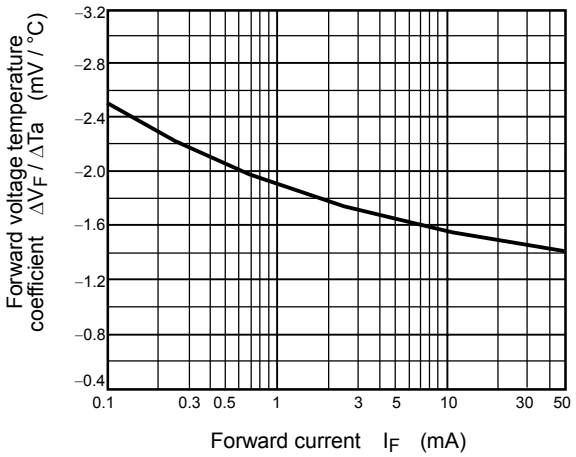
I_{FP} – D_R



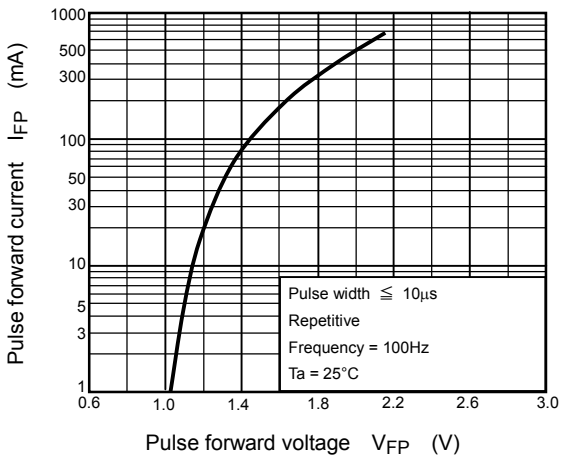
I_F – V_F



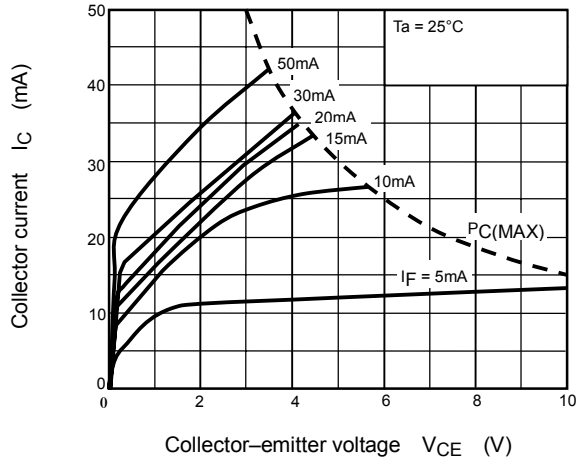
$\Delta V_F / \Delta Ta$ – I_F



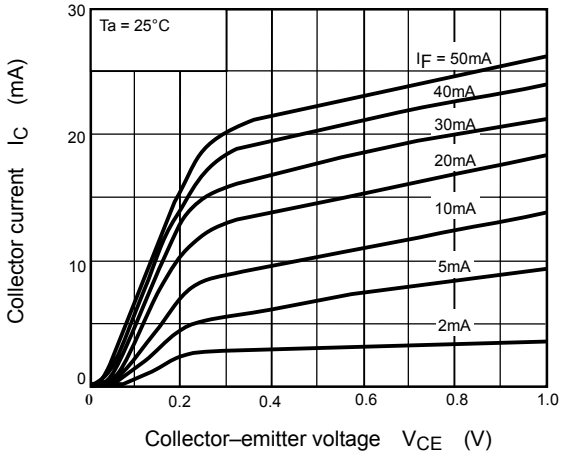
I_{FP} – V_{FP}



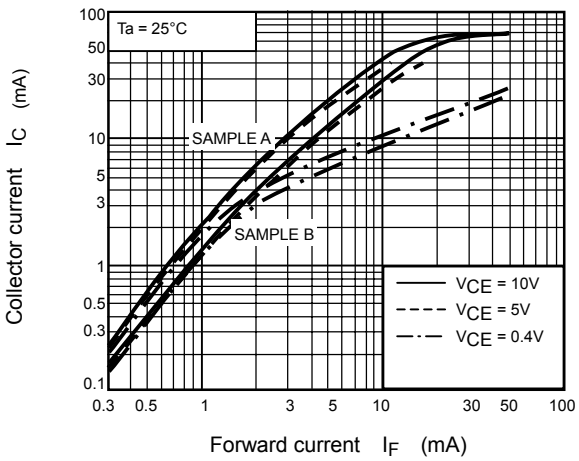
$I_C - V_{CE}$



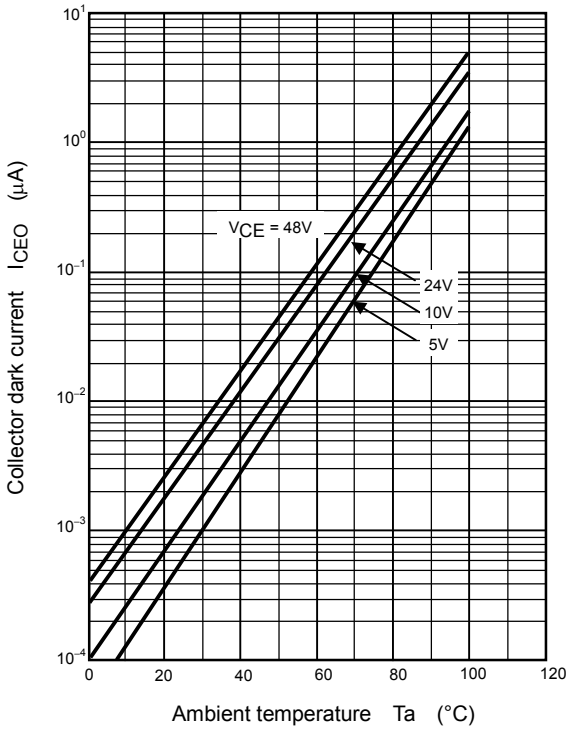
$I_C - V_{CE}$



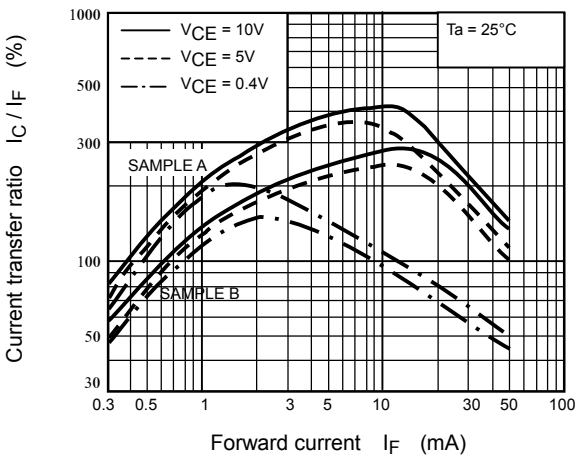
$I_C - I_F$



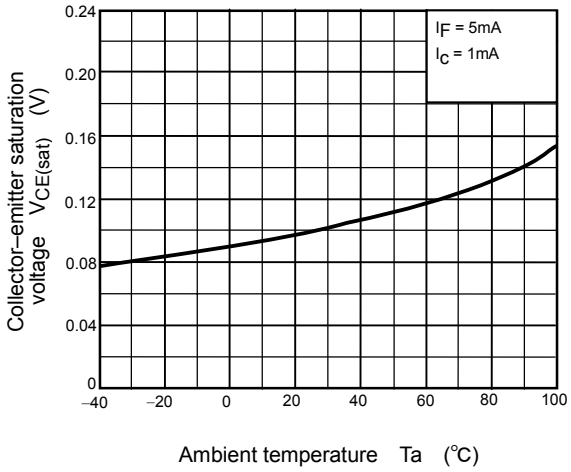
$I_{CEO} - Ta$



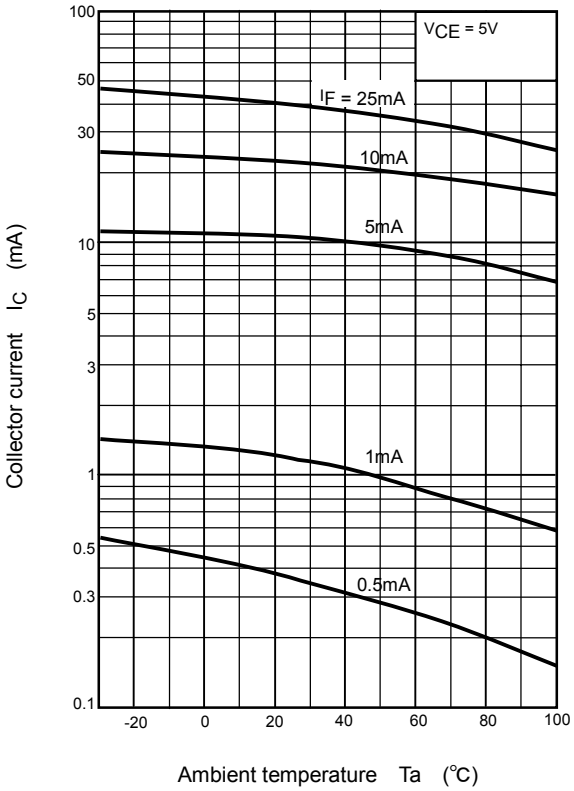
$I_C / I_F - I_F$



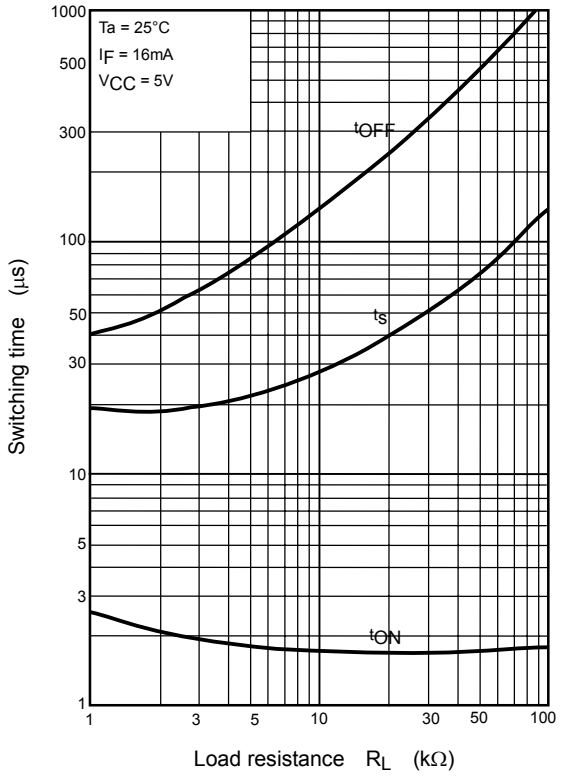
$V_{CE(sat)}$ – Ta



I_C – Ta



Switching Time – RL



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